TOSHIBA Photocoupler Photo Relay

TLP227GA, TLP227GA-2

Modem
Telecommunications
PBXs

The Toshiba TLP227GA series consist of an infrared-emitting diode optically coupled to a photo-MOSFET in a 4-pin DIP or a 8-pin DIP package, and has a peak off-State voltage of $400~\rm V$.

• Normally off function

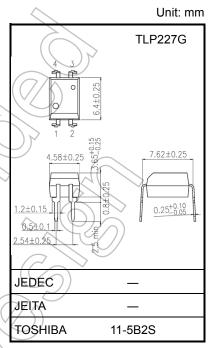
TLP227GA : DIP4 (1 form A)
 TLP227GA-2 : DIP8 (2 form A)

 Peak off-state voltage : 400 V (min)
 Trigger LED current : 3 mA (max)
 On-state current : 120 mA (max)
 On-state resistance : 35 Ω (max)
 Isolation voltage : 2500 Vrms (min)

• UL-recognized : UL 1577, File No.E67349

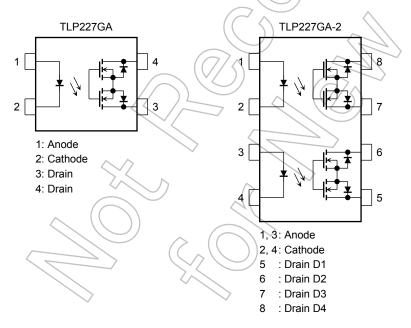
cUL-recognized : CSA Component Acceptance Service No.5A

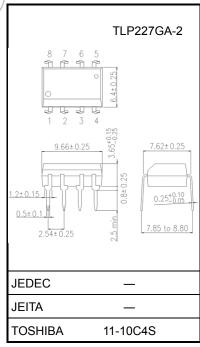
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Weight: 0.26 g (typ.)

Pin Configuration (top view)





Weight: 0.54 g (typ.)

Start of commercial production 2000-04

Absolute Maximum Ratings (Ta = 25°C)

$ \begin{array}{ c c c c c } \hline Characteristics & Symbol & Rating & Unit \\ \hline \\ Forward current & IF & 50 & mA \\ \hline Forward current derating & (Ta \geq 25^{\circ}C) & \Delta I_F/^{\circ}C & -0.5 & mA/^{\circ}C \ Peak forward current (100~\mu s pulse, 100~pps) & I_{FP} & 1 & A \ Reverse voltage & VR & 5 & V \ Diode power dissipation & P_D & 50 & mW \ Diode power dissipation derating & (Ta \geq 25^{\circ}C) & \Delta P_D/^{\circ}C & -0.5 & mW/^{\circ}C & Junction temperature & T_J & 125 & ^{\circ}C & $								1
Forward current derating (Ta \geq 25°C)		Characteristics			Symbol	Rating	Unit	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		Forward current			lF	50	mA	
Reverse voltage VR 5 V		Forward current derating (Ta ≥ 25°C)			ΔI _F /°C	-0.5	mA/°C	
Diode power dissipation P_D 50 mW Diode power dissipation derating (Ta \geq 25°C) ΔP_D /°C -0.5 mW/°C Junction temperature P_D 125 °C Off-state output terminal voltage P_D 125 °C Off-state output terminal voltage P_D 125 °C On-state current P_D 120 mA Diode power dissipation derating (Ta \geq 25°C) P_D 120 mA Diode power dissipation derating (Ta \geq 25°C) P_D 120 mA Diode power dissipation derating (Ta \geq 25°C) P_D 120 mA Diode power dissipation derating (Ta \geq 25°C) P_D 121 P_D 1227GA P_D 125 °C P_D 126 Storage temperature range P_D 126 °C P_D 127 P_D 128 °C P_D 128 °C P_D 129 °C P_D					IFP	1	Α	
Diode power dissipation derating (Ta $\geq 25^{\circ}$ C) $\triangle P_D$ /°C -0.5 mW/°C Junction temperature P_D 125 °C Off-state output terminal voltage P_D VOFF 400 V OFF 400 V OFF 400 ON-state current TLP227GA-2 Both channel Don-state current rating (Ta $\geq 25^{\circ}$ C) TLP227GA-2 Both channel Doutput power dissipation Output power dissipation Output power dissipation Output power dissipation TLP227GA TLP227GA-2 Doutput power dissipation Output power dissipation Output power dissipation TLP227GA TLP227GA-2 TLP22	Le	Reverse volt	age		VR	5	V	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Diode power	dissipation		P _D	50	mW	
Off-state output terminal voltage		Diode power	dissipation der	ating (Ta ≥25°C)	ΔP _D /°C	-0.5	mW/°C	// 5)
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		Junction temperature			Tj	125	°C	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		Off-state out	put terminal vol	tage	Voff	400	(v)	7
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			TLP227GA	27GA		0		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				One channel	Ion	120	mA	$\mathcal{A}($
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				Both channel				
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			TLP227GA					$> (\bigcirc)_{\angle}$
Output power dissipation Output power dissipation Output power dissipation derating (Ta \geq 25°C) Junction temperature Storage temperature range TLP227GA TLP22	ctor	rating	ting TI P227GA-2	One channel	Δlon/°C	-1.2	mA/°C	1
$\begin{array}{ c c c c c c c c }\hline Output power dissipation & TLP227GA-2 & 600 & mW \\\hline Output power dissipation derating (Ta \geq 25^{\circ}\text{C}) & TLP227GA \\\hline Junction temperature & Tj & 125 & °C \\\hline Storage temperature range & Tstg & -55 to 125 & °C \\\hline Operating temperature range & Topr & -40 to 85 & °C \\\hline Lead soldering temperature (10 s) & Tsol & 260 & °C \\\hline \end{array}$	Dete			Both channel			/	7
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		Output power dissipation		TLP227GA	Do	432	m\\\	$(\mathcal{S}_{\mathcal{O}})$
				TLP227GA-2	Po	600	IIIV	,
Indicating (Ta 2 25 C) TLP227GA-2		denoting (Te > 25°C)		TLP227GA	ADov°C	-4.32	~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~~))
Storage temperature range T _{stg} -55 to 125 C Operating temperature range T _{opr} -40 to 85 C Lead soldering temperature (10 s) T _{sol} 260 °C				TLP227GA-2	ДРОЛС	-6,0	IIIW / C	
Operating temperature range Topr -40 to 85 °C Lead soldering temperature (10 s) Tsol 260 °C		Junction tem	Junction temperature			125	°C)	
Lead soldering temperature (10 s) T _{sol} 260 °C	Stor	age temperat	ure range		Tstg	−55 to 125	°¢	
200 mg (mp + 100 mg)	Оре	Operating temperature range			Topr	-40 to 85	°C	
Isolation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1) BVs 2500 Vrms	Lea	Lead soldering temperature (10 s)				260	°C	
	Isola	ation voltage (AC, 60 s, R.H.	≤ 60 %) (Note 1)	BVs	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{DD}	_	_	320	٧
Forward current	lF	5	7.5	25	mA
On-state current	Ion	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	IR	V _R = 5 V	_	_	10	μА
	Capacitance	Ст	VF = 0 V, f = 1 MHz	/-	30	_	pF
Detector	Off-state current	loff	Voff = 400 V	\sim	}-	1	μА

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	lfT	ION = 120 mA	_ <	71	3	mA
On-state resistance	Ron	ION = 120 mA, IF = 5 mA	7	18	35	Ω

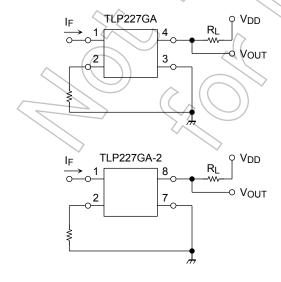
Isolation Characteristics (Ta = 25°C)

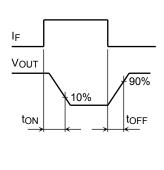
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	Vs = 0 V, f = 1 MHz		0.8	-	pF
Isolation resistance	Rs	Vs = 500 V, R.H. ≦ 60 %	5 × 10 ¹⁰	10 ¹⁴	-	Ω
Isolation voltage	BVs	AC, 60 s	2500	_	1	Vrms

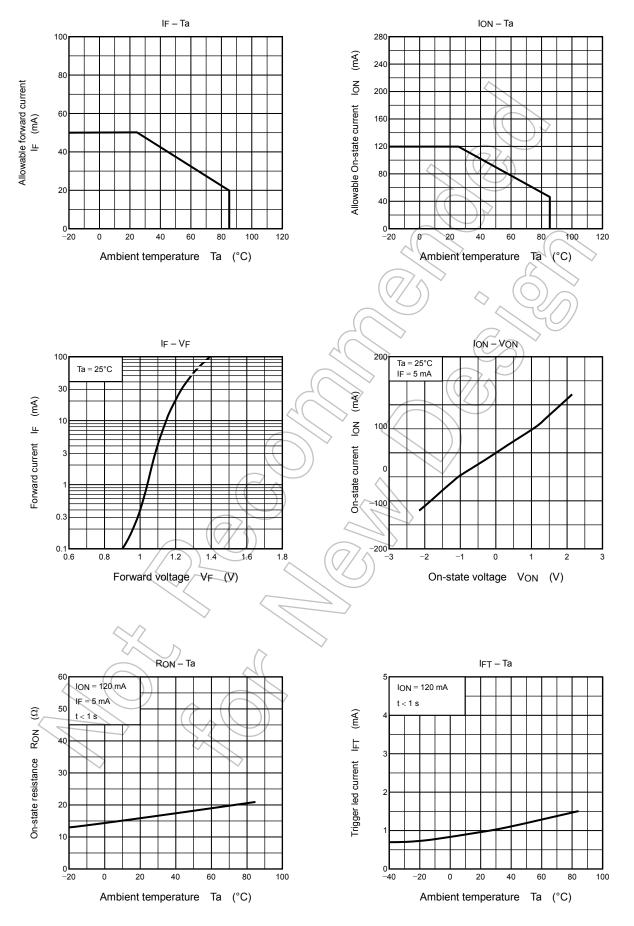
Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	ton	R _L = 200 Ω	_	_	1	ma
Turn-off time	toff	$V_{DD} = 20 \text{ V}, \text{ Jp} = 5 \text{ mA}$ (Note 2))	_	1	ms

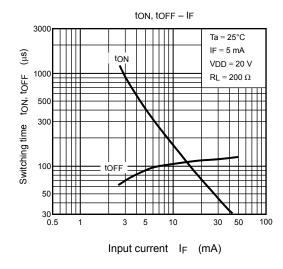
Note 2: Switching time test circuit

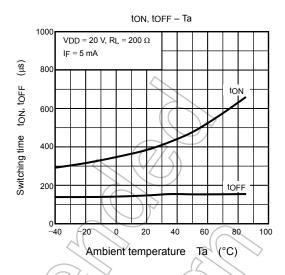


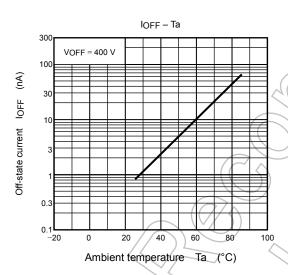




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.







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